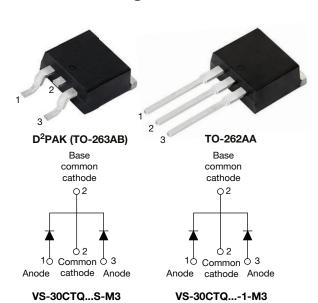


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High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} 2 x 15 A						
V_{R}	35 V, 40 V, 45 V					
V _F at I _F	0.56 V					
I _{RM}	15 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	20 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 175 °C T_J operation
- · Center tap configuration
- Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-30CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES U								
I _{F(AV)}	Rectangular waveform	30	Α					
V _{RRM}		35 to 45	V					
I _{FSM}	t _p = 5 μs sine	1060	Α					
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.56	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-30CTQ035S-M3 VS-30CTQ040S-M3 VS-30CTQ045S-M3 VS-30CTQ045S-M3 VS-30CTQ045-1-M3 VS-30CTQ045-1-M3 VS-30CTQ045-1-M3							
Maximum DC reverse voltage	V_R	25	40	ΛE	V		
Maximum working peak reverse voltage	V_{RWM}	35 40 45 M					



VS-30CTQ...S-M3, VS-30CTQ...-1-M3 Series

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 127 °C	30					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated	1060	Α			
non-repetitive surge current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	265				
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 3.0 \text{A}, L = 4.40 \text{mH}$		20	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T ₁ maximum V _A = 1.5 x V _B typical		3.0	Α			

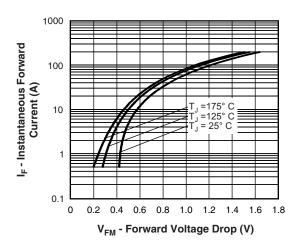
ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
		15 A	T _{.1} = 25 °C	0.62			
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	30 A	1j=25 C	0.76	V		
See fig. 1		15 A	T 105 °C	0.56			
		30 A	T _J = 125 °C	0.70			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	2	mA		
See fig. 2	'RM '''	T _J = 125 °C	v _R = nateu v _R	15	IIIA		
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		900	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 mr	8.0	nΗ			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS		
Maximum junction and stor temperature range	age	T _J , T _{Stg}		-55 to 175	°C		
Maximum thermal resistand junction to case per leg	ce,	В	DC operation See fig. 4	3.25			
Maximum thermal resistance, junction to case per package		- R _{thJC}	DC operation	1.63 °C/			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50			
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
wounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK (TO-263AB)	30CTC 30CTC 30CTC	040S		
			Case style TO-262AA	30CTC 30CTC 30CTC	040-1		

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Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

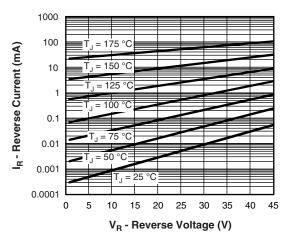


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

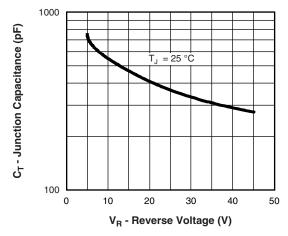


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

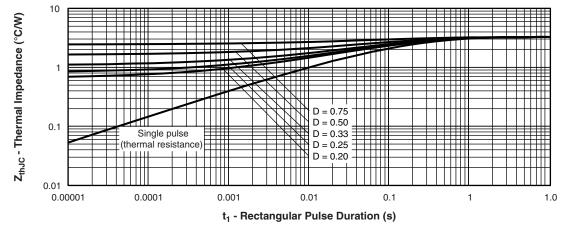


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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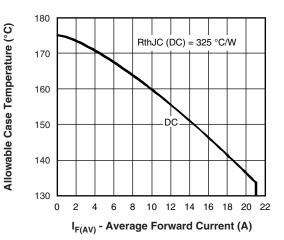


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

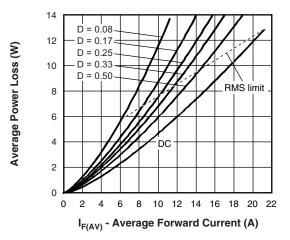


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

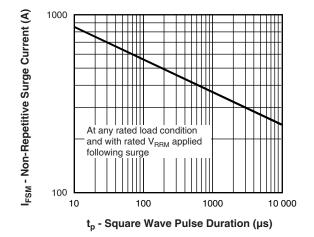


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

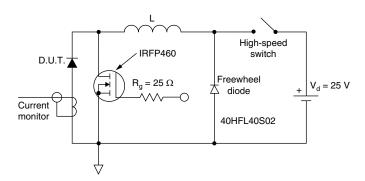


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6);

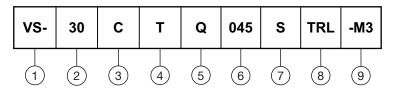
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 Pd_{REV} = inverse power loss = V_{R1} x I_{R} (1 - D); I_{R} at V_{R1} = 80 % rated V_{R}

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

Circuit configuration: C = common cathode

- T = TO-220

- Schottky "Q" series

035 = 35 V 040 = 40 V 045 = 45 V

6 - Voltage ratings
 7 - • S = D²PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D²PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D²PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-30CTQ035S-M3	50	Antistatic plastic tubes						
VS-30CTQ035STRL-M3	800	13" diameter plastic tape and reel						
VS-30CTQ035STRR-M3	800	13" diameter plastic tape and reel						
VS-30CTQ045S-M3	50	Antistatic plastic tubes						
VS-30CTQ045STRL-M3	800	13" diameter plastic tape and reel						
VS-30CTQ045STRR-M3	800	13" diameter plastic tape and reel						
VS-30CTQ045-1-M3	50	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Differsions	TO-262AA	www.vishay.com/doc?96165				
Dort marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	IOTES SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOIES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Vishay Semiconductors

TO-262

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	INCHES			
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.10	D BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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